## TRANSMITTAL OF FORMAL DRAWINGS

Docket No. 00750425AA

RRAMMIcation Of:

H. Park, et al.

Serial No.	Filing Date	Confirmation No.	Examiner	Art Unit
09/924,318	08/08/01		Unassigned	1765

Invention:

METHOD OF BUILDING A CMOS STRUCTURE ON THIN SOI WITH SOURCE/DRAIN ELECTRODES FORMED BY IN SITU

Address to:

**Assistant Commissioner for Patents** Washington, D.C. 20231

Transmitted herewith are:

4 sheets of formal drawing(s) for this application.

X Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c).

Hgnature

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PATENT TRADEMARK OFFICE

Dated:

April 4, 2003

I certify that this document and attached formal drawings are being deposited on U.S. Postal Service as first class mail under 37 C.F.R. 1.8

and addressed to the Assistant Commissioner for Patents. Washington, D.C. 20231.

Signature of Person Mailing Correspondence

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